

Direct measurements of the properties of Thick-GEM reflective photocathodes

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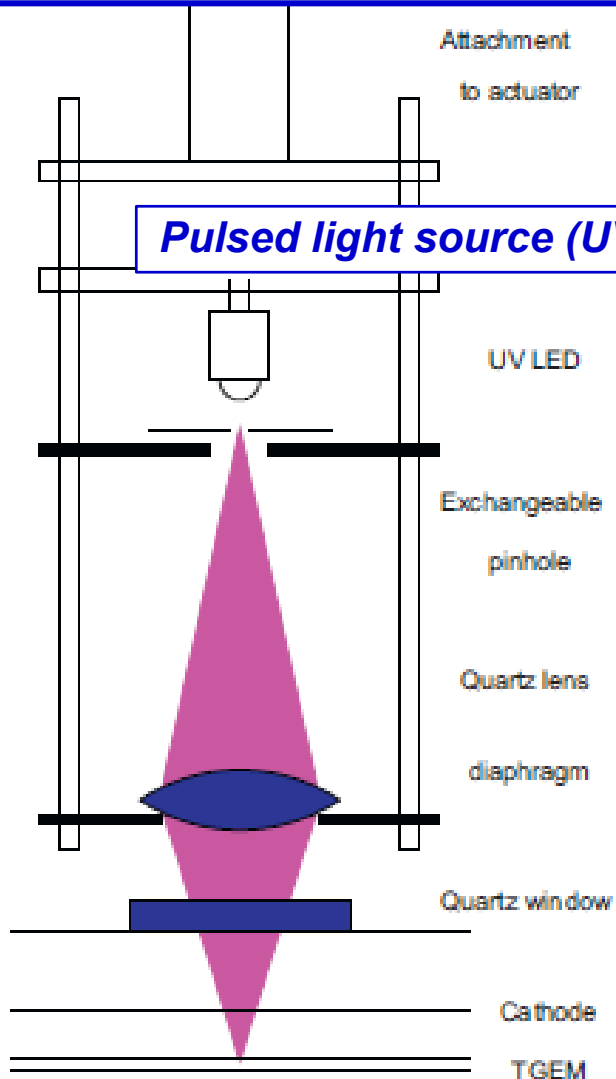
^d*Physics Department, University of Aveiro, Aveiro, Portugal*

Submitted to NIMA

**NEW:
Understanding detectors
using LEOPARD**

REMINDER ABOUT LEOPARD

Scanning with this device

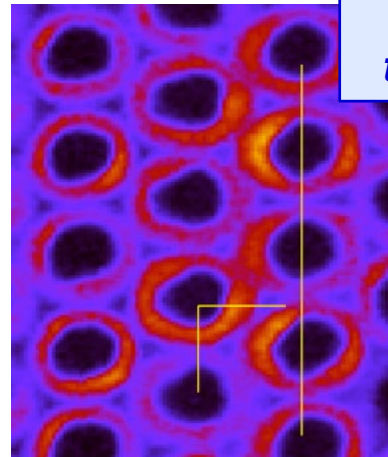


Typical light spot-size $\leq 100 \mu\text{m}$

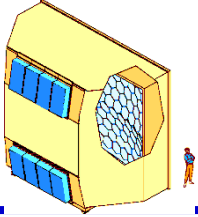
Studies

- Operation in “single photon mode”
- At each point an (exponential) amplitude spectrum is collected
- LEOPARD provides, at the same time:
 - **Gain maps**: mean value of the exponential distribution
 - **Efficiency maps** :
 - $n_{\text{hits}} / n_{\text{pulses}}$ (depends on thr. & gain): **measured YIELD**
 - extrapolated including hits regeted by thr. : **extrapolated YIELD**

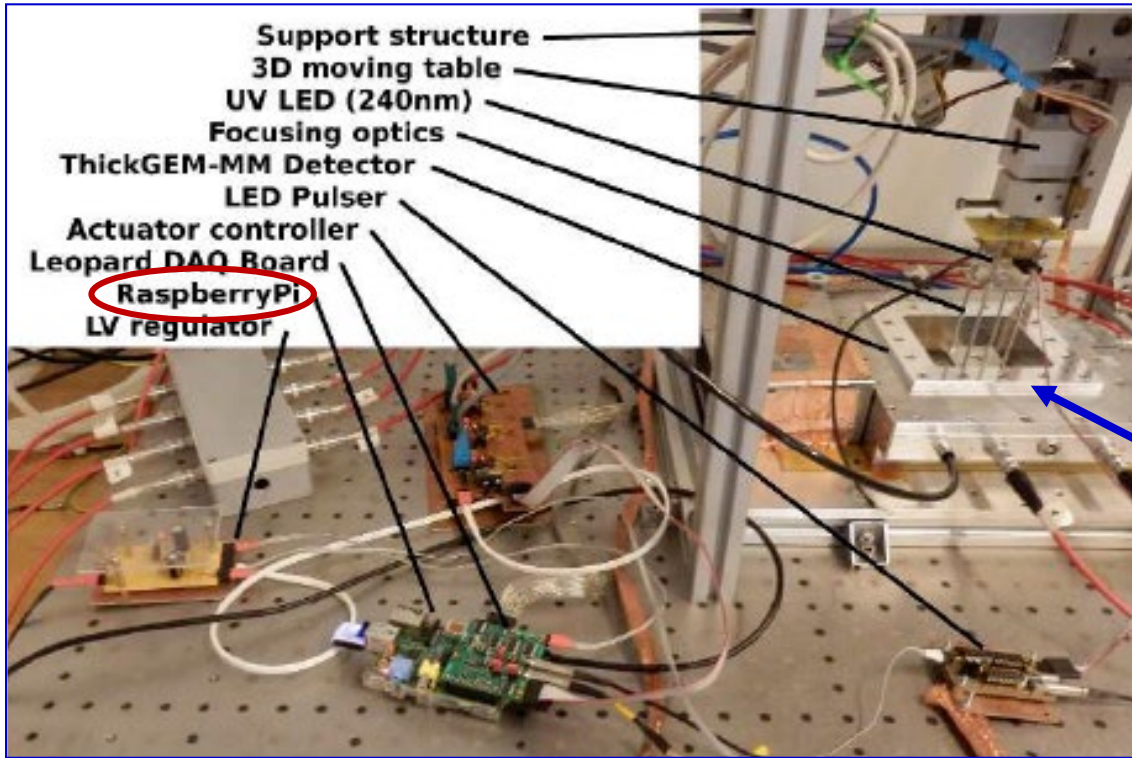
From first images
the nickname : LEOPARD



- More recently used for quality control of THGEMS and GEMs (WIGNER activity)



EQUIPMENT & SETUP

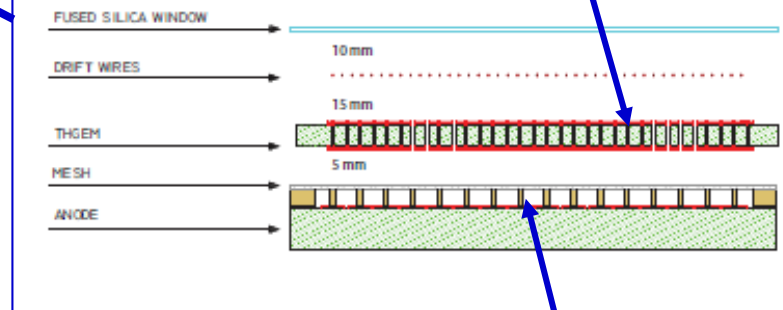


- Support structure
- 3D moving table
- UV LED (240nm)
- Focusing optics
- ThickGEM-MM Detector
- LED Pulsar
- Actuator controller
- Leopard DAQ Board
- RaspberryPi**
- LV regulator

THGEM	Hole diameter	Pitch	Thickness	Rim
Name	[μm]	[μm]	[μm]	[μm]
M1-III	400	800	400	0
DESTRO-I	400	800	400	5
C3HR-II	400	800	400	50
M2.4-G	400	800	600	0
M2.1-II	300	800	400	0

THGEM been studied

Ar:CH₄ = 30:70



MM for amplification

An absolute MUST: high rate DAQ

**In fact: for a typical measurement pitch of 100 μm
 \rightarrow 10k points/cm² with 20k triggers/point to collect ~ 1000 entries / spectrum**

DAQ, collected event rate : 130 kHz

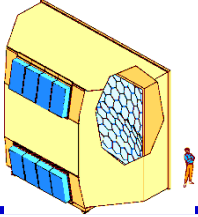
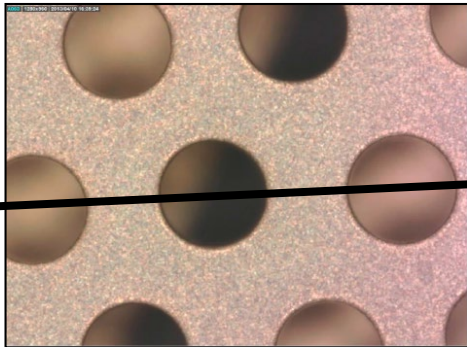
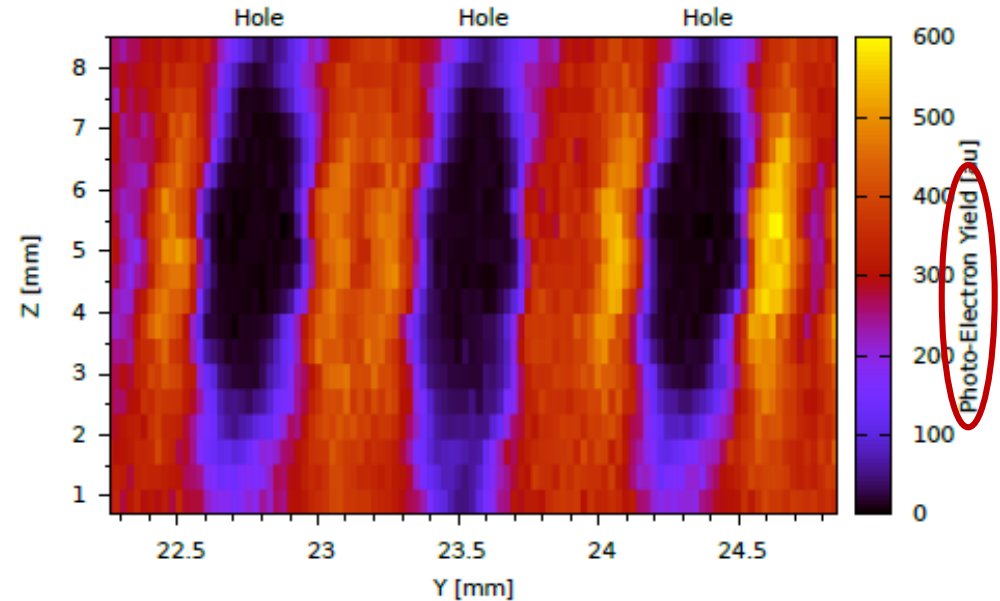


IMAGE FOCUSING

For each THGEM to be studied



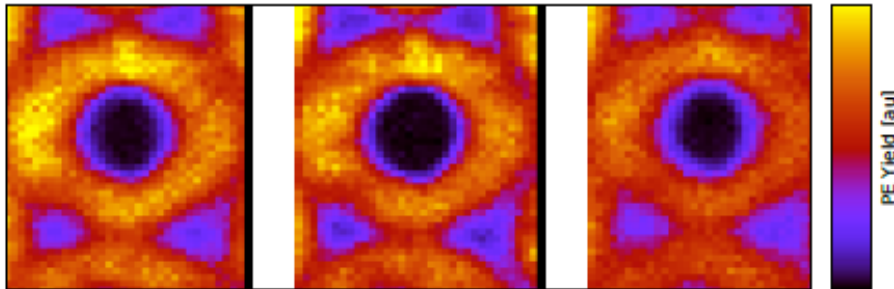
Scanning along
this line at
different heights



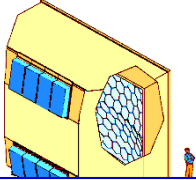
-1 mm

focus

+ 1 mm



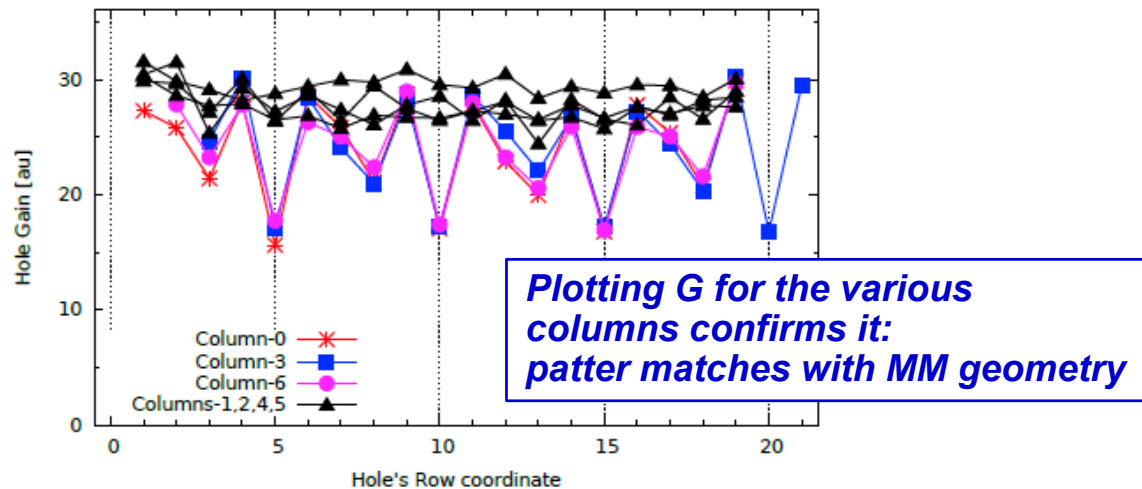
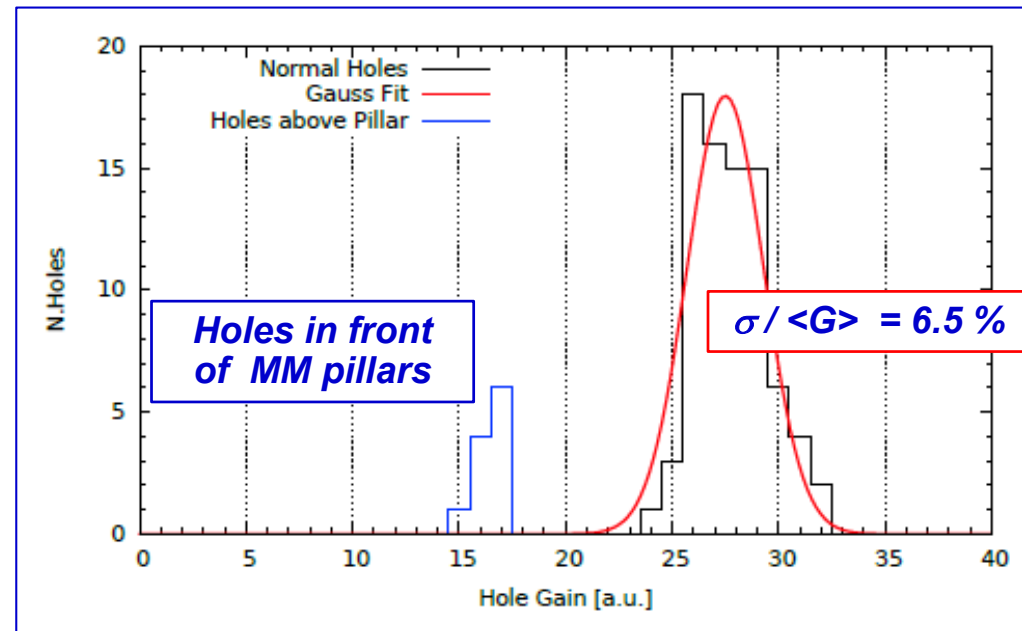
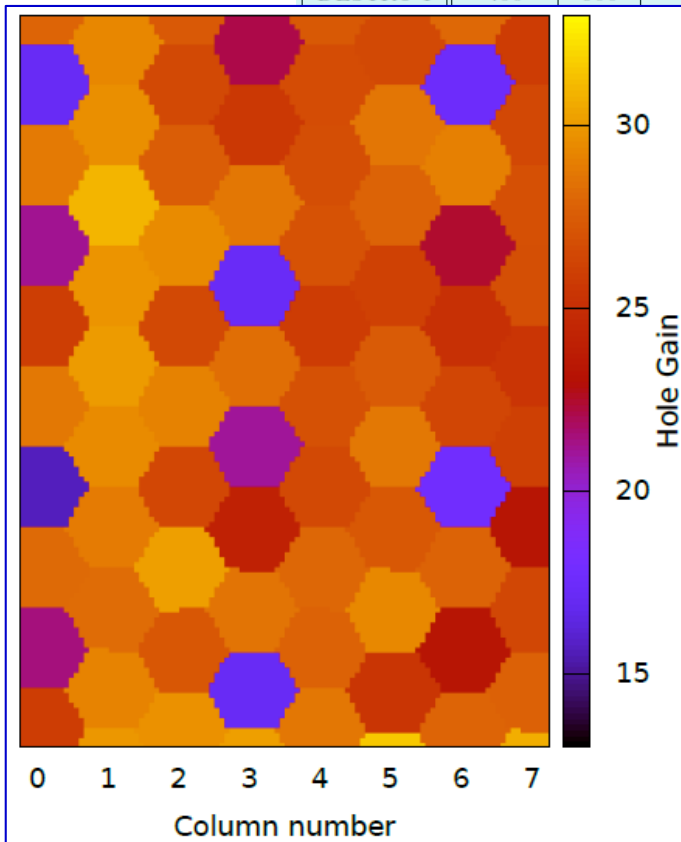
Cross-check scanning in
the horizontal plane at
different heights

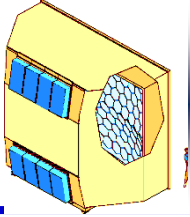


GAIN UNIFORMITY

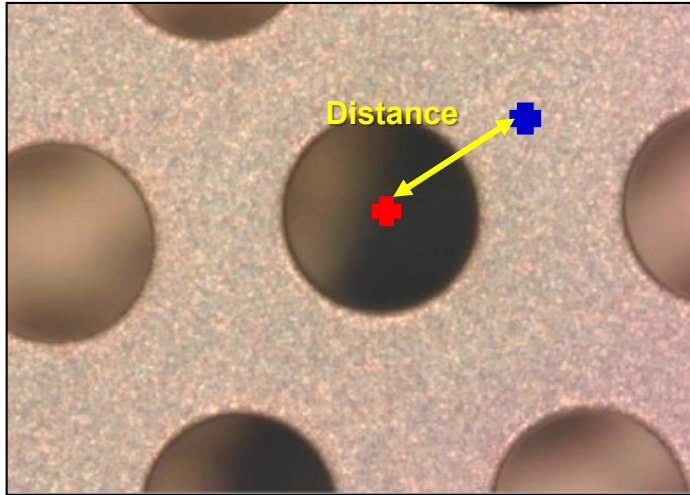
GAIN UNIFORMITY IN A GOOD INDUSTRIAL THGEM

THGEM	Hole diameter	Pitch	Thickness	Rim
Name	[μm]	[μm]	[μm]	[μm]
M1-III	400	800	400	0
DESTRO-I	400	800	400	5
			400	50
			600	0
			400	0

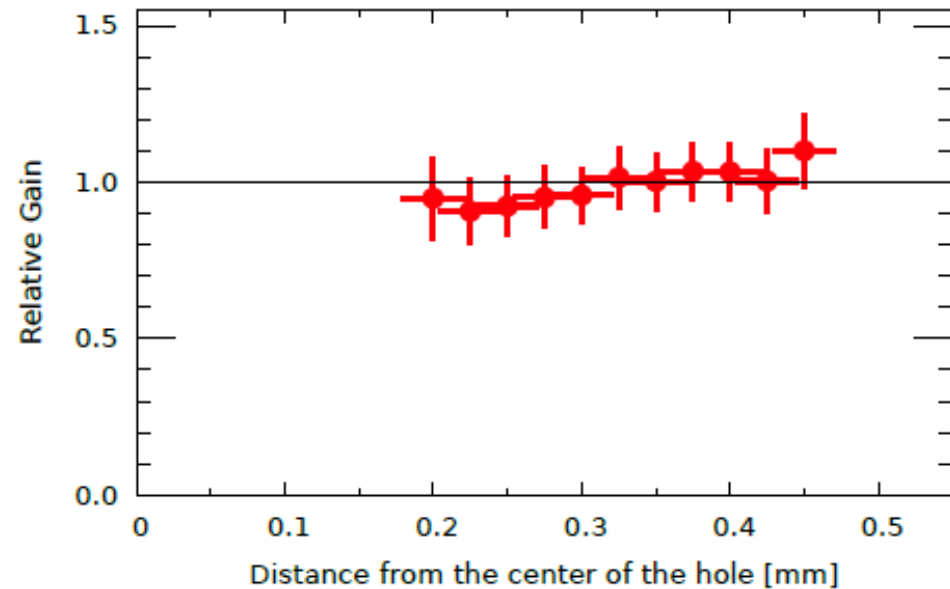




GAIN UNIFORMITY vs e^- GENERATION POINT

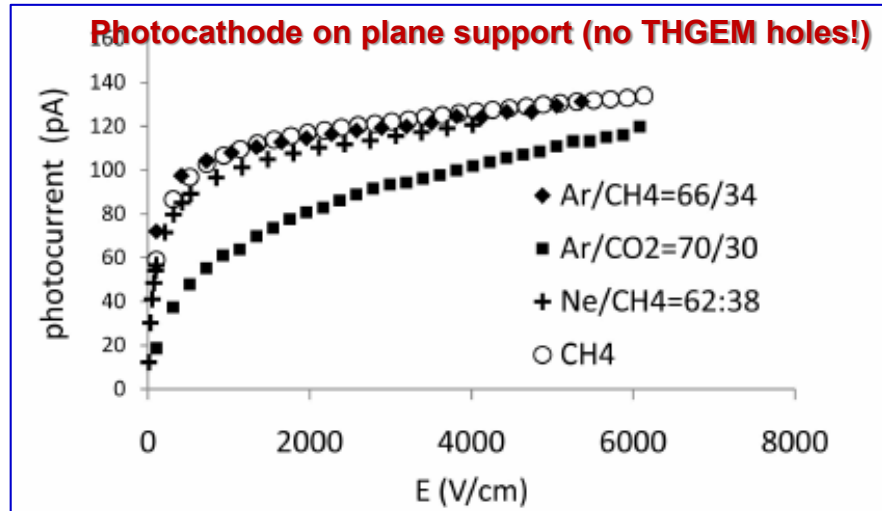


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PHOTOELECTRON EXTRACTION

- A few introductory elements to understand the issue

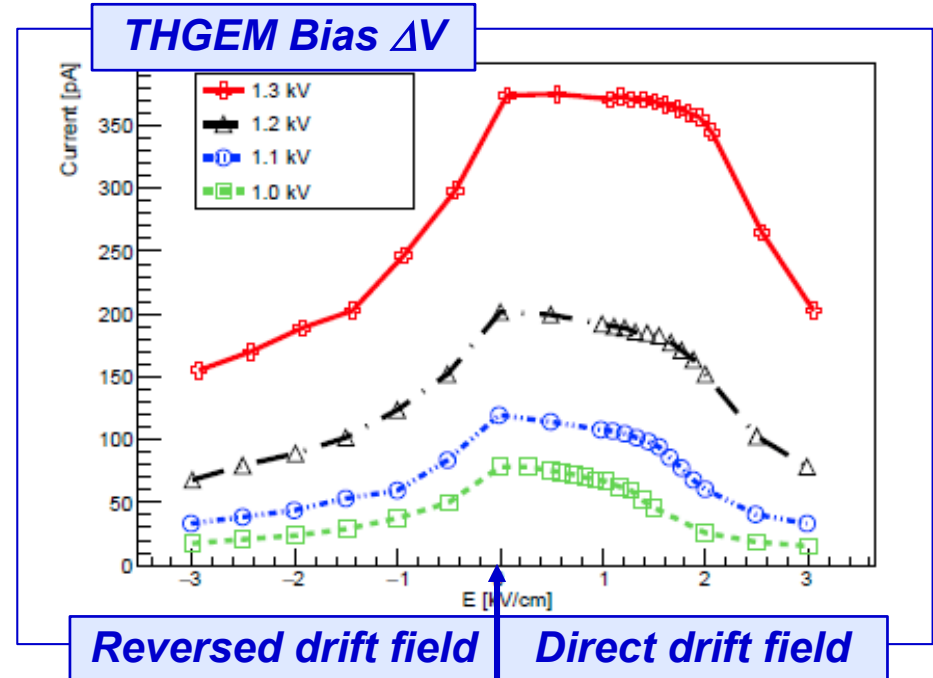


Preliminary measurements on THGEM

Here **E** is the sum of the field from biasing voltage + drift field

In this preliminary exercise the anode current has been measured

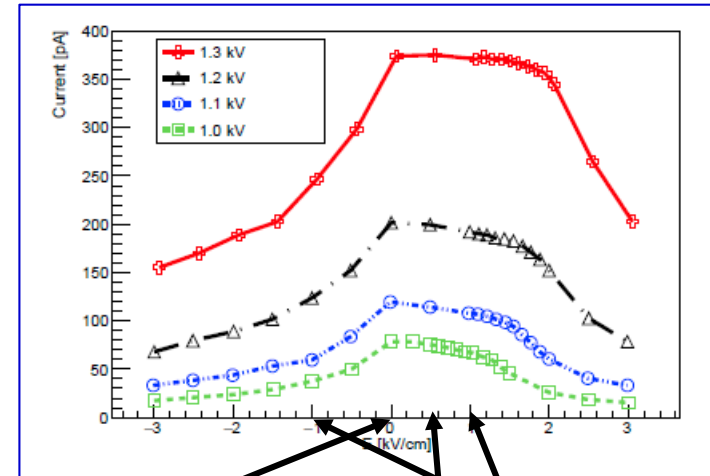
KEY point
for gaseous PDS



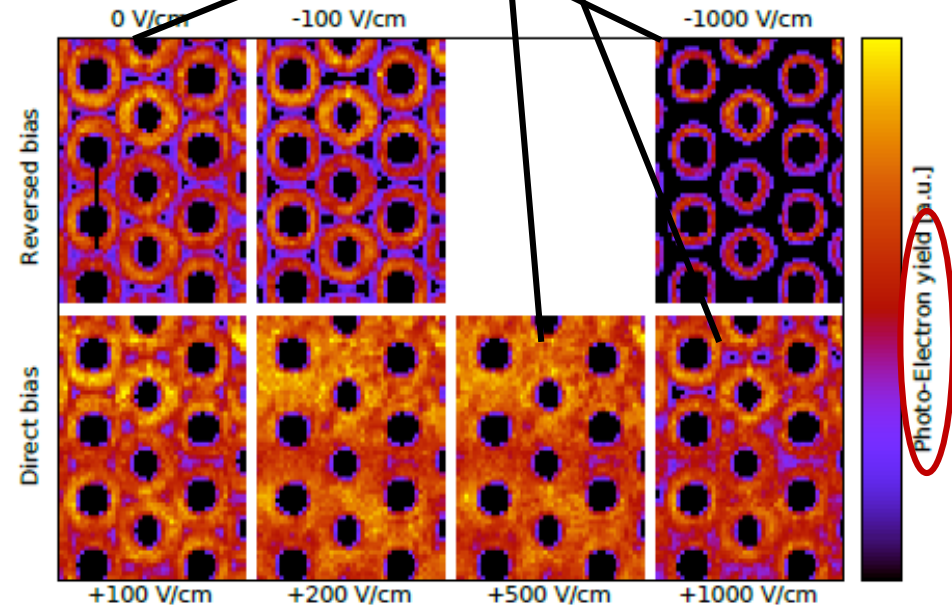
PHOTOELECTRON EXTRACTION

A picture of the detailed behavior by LEOPARD

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Photoelectron extraction vs Drift field



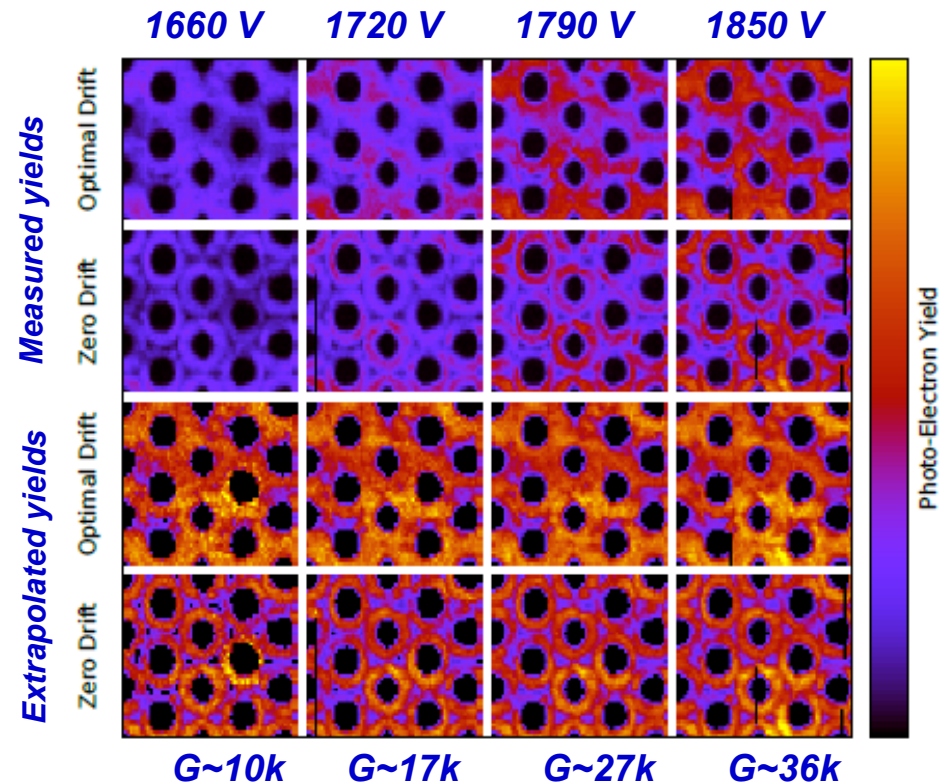
PHOTOELECTRON EXTRACTION

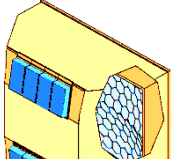
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Photoelectron extraction vs GAIN

A comment: non-ideal noise and threshold ($\sim 11\text{k e}$ equivalent) for these tests



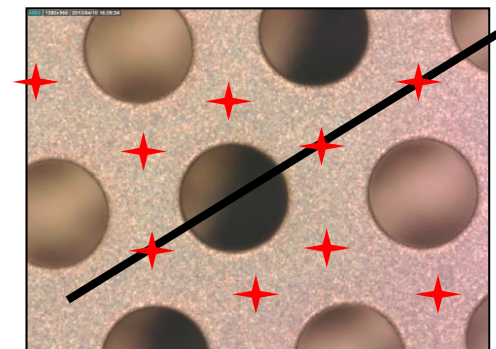


PHOTOELECTRON EXTRACTION

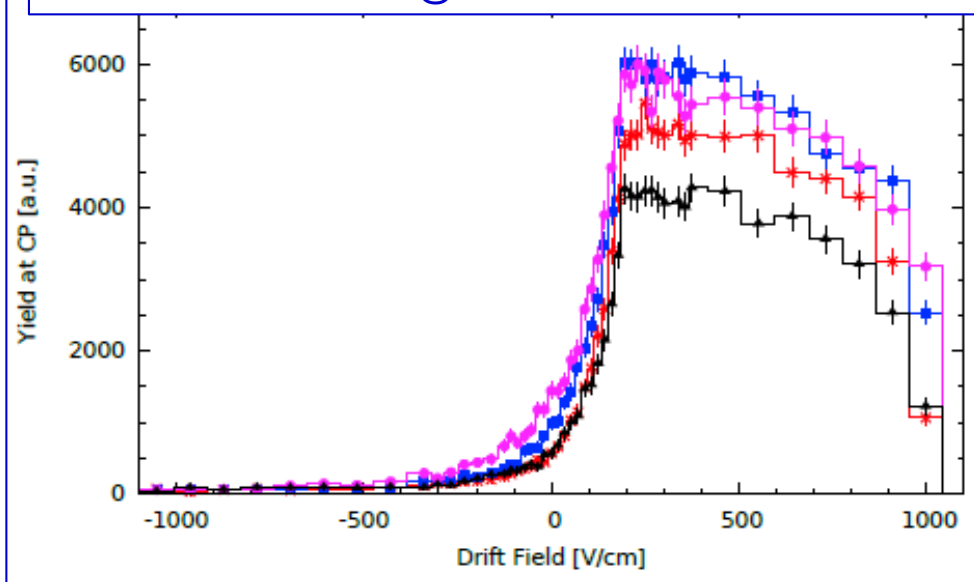
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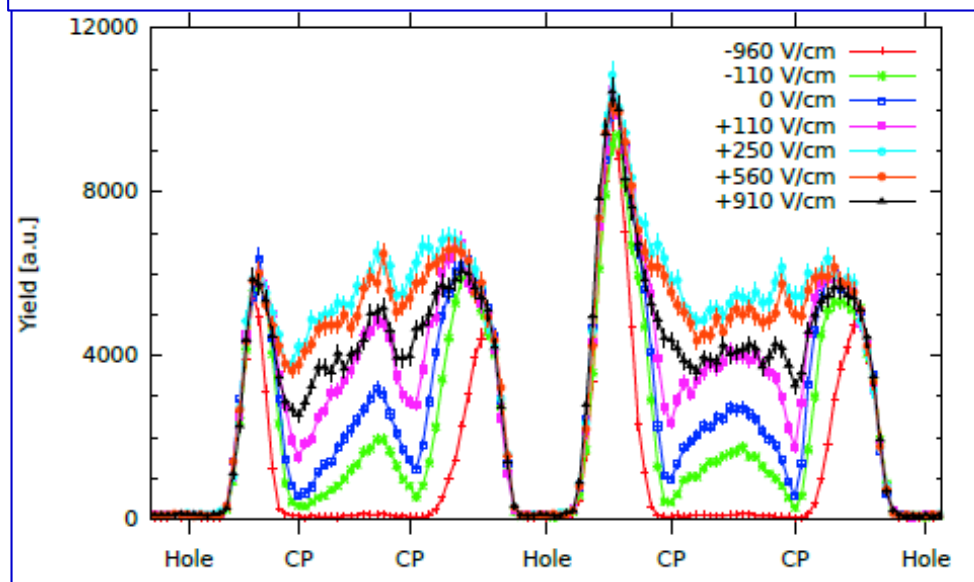
Critical Point (CP) & Critical Line (CL):
A faster approach for more studies

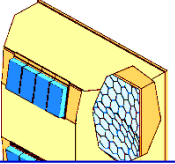


EXTRAPOLATED YIELS @ 4 different CPs vs DRIFT FIELD



EXTRAPOLATED YIELS along a CL varying the DRIFT FIELD





PHOTOELECTRON EXTRACTION

- A picture of the detailed behavior by LEOPARD

Comparing different THGEM geometries:

Extrapolated yields in 2D plots

x-axis – drift field

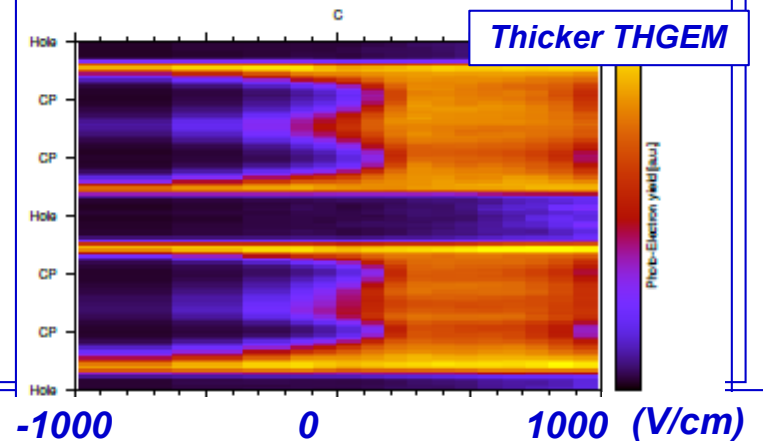
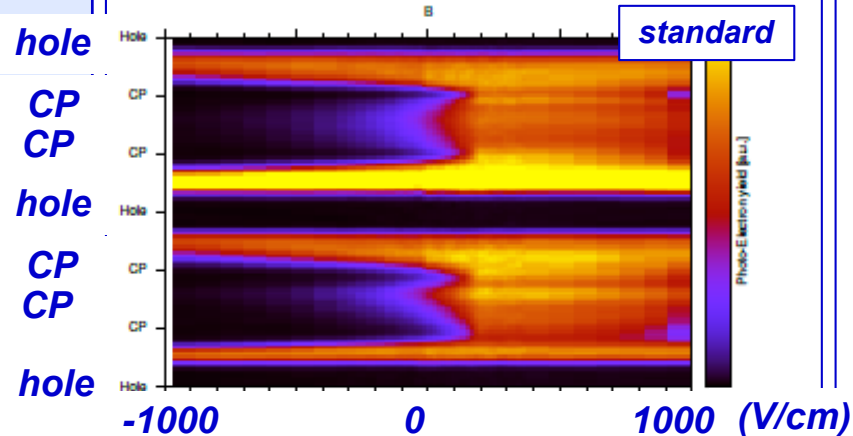
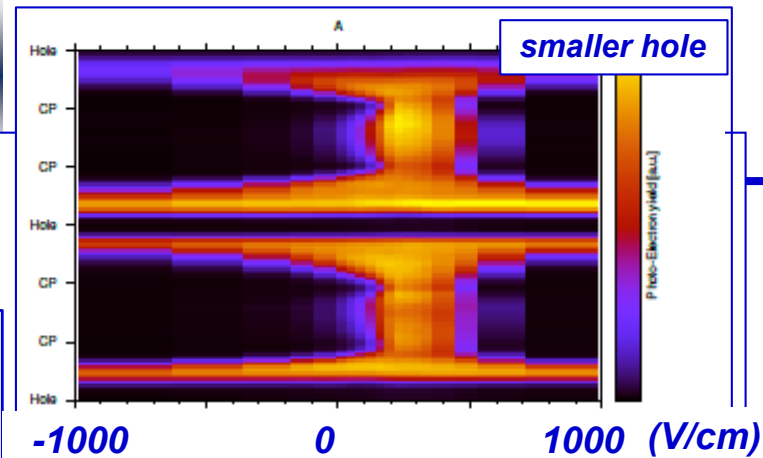
y-axis – location along a CL

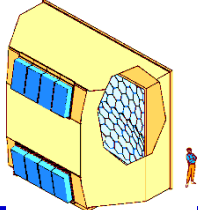
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Standard (used at COMPASS)

Thicker THGEM: higher gain !

smaller hole: more active surface !
(78% \rightarrow 87%)



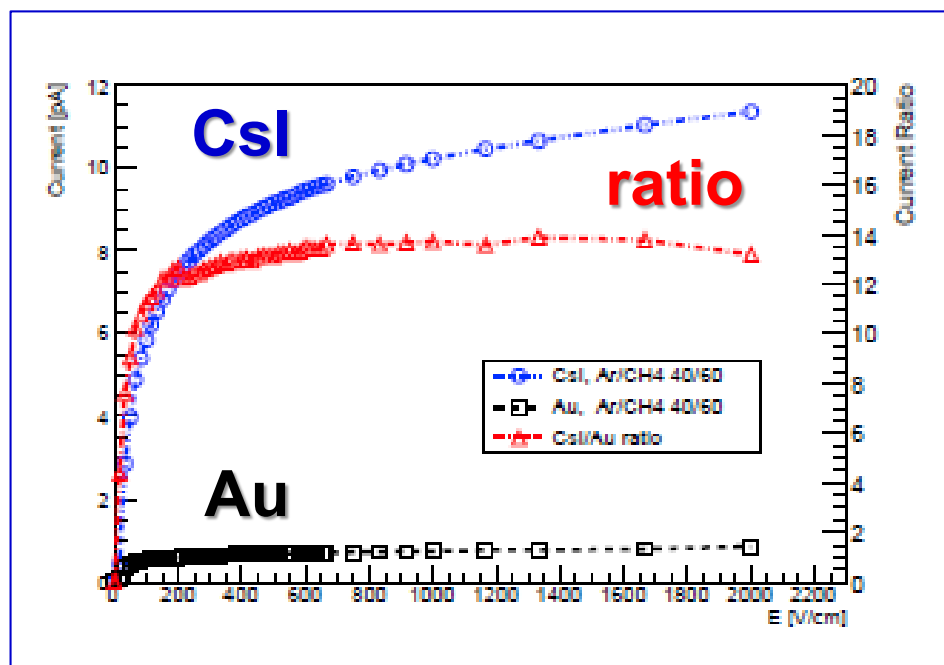


PHOTOELECTRON EXTRACTION

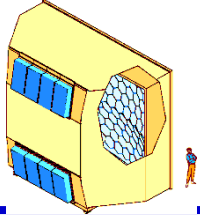
All this extracting from gold (UV LEDs below 245 nm not available)

Is it valid for CsI ?

Photocurrent in gas from different photoconverters



Ar:CH₄=60:40.



(SHORT) CONCLUSIONS

- To progress you need
 - Clever tools
 - Well defined questions that can be address with good tools
- We had both and, therefore, **we have learned a lot**

THANK YOU FOR YOUR ATTENTION